

Data sheet acquired from Harris Semiconductor SCHS070B – Revised June 2003

CMOS Dual 4-Bit Latch

High-Voltage Types (20-Volt Rating)

CD4508B dual 4-bit latch contains two identical 4-bit latches with separate STROBE, RESET, and OUTPUT DISABLE controls. With the STROBE line in the high state, the data on the "D" inputs appear at the corresponding "Q" outputs provided the DISABLE line is in the low state. Changing the STROBE line to the low state locks the data into the latch. A high on the reset line forces the outputs to a low level regardless of the state of the STROBE input. The outputs are forced to the high-impedance state for bus line applications by a high level on the DISABLE input.

The CD4508B types are supplied in 24-lead hermetic dual-in-line ceramic packages (F3A suffix), 24-lead dual-in-line plastic packages (E suffix), 24-lead small-outline packages (M, M96, and NSR suffixes), and 24-lead thin shrink small-outline packages (PW and PWR suffixes).

The CD4508B is similar to industry type MC14508.

Features:

- Two independent 4-bit latches
- Individual master reset for each 4-bit latch
- 3-state outputs with high-impedance state for bus line applications
- Medium-speed operation: tpHL = tpLH = 70 ns (typ.) at VDD = 10 V and CL = 50 pF
- 100% tested for quiescent current at 20 V
- 5-V, 10-V, and 15-V parametric ratings
- Standardized, symmetrical output characteristics
- Maximum input current of 1 μA at 18 V over full package-temperature range; 100 nA at 18 V and 25°C
- Noise margin (full package-temperature range) =

1 V at VDD = 5 V

2 V at V_{DD} = 10 V

2.5 V at VDD = 15 V

 Meets all requirements of JEDEC Tentative Standard No. 13B,"Standard Specifications for Description of 'B' Series CMOS Devices"

Applications:

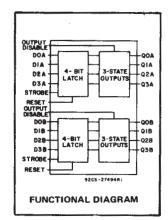
- Buffer storage
- Holding registers
- Data storage and multiplexing

MAXIMUM RATINGS, Absolute-Maximum Values: DC SUPPLY-VOLTAGE RANGE. (VDD)

DO 3011 E. 10E1/1GE 151114E, (1DD)	
Voltages referenced to VSS Terminal)0.5V to +20V	
INPUT VOLTAGE RANGE, ALL INPUTS0.5V to V _{DD} +0.5V	
DC INPUT CURRENT, ANY ONE INPUT	
POWER DISSIPATION PER PACKAGE (PD):	
For T _A = -55°C to +100°C	
For T _A = +100°C to +125°C Derate Linearity at 12mW/°C to 200mW	
DEVICE DISSIPATION PER OUTPUT TRANSISTOR	
FOR TA = FULL PACKAGE-TEMPERATURE RANGE (All Package Types)	
OPERATING-TEMPERATURE RANGE (T _A)55°C to +125°C	
STORAGE TEMPERATURE RANGE (T _{stq})65°C to +150°C	
LEAD TEMPERATURE (DURING SOLDERING):	
At distance 1/16 ± 1/32 inch (1.59 ± 0.79mm) from case for 10s max	

RECOMMENDED OPERATING CONDITIONS at $T_A = 25^{\circ}$ C, Except as Noted. For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

	V _{DD}	LIM	IITS	
CHARACTERISTIC	(V)	Min.	Max.	UNITS
Supply-Voltage Range (For TA = Full Package- Temperature Range)		3	18	V
	5	200	_	
Reset Pulse Width, tW(R)	10	140	-	
	15	100	_	
	5	140	_	1
Strobe Pulse Width, tW(st)	10	80	-	
	15	70]
	5	50	_	ns
Setup Time, t _{SU}	10	30	-	1
	15	20	_	
	5	0] .
Hold Time, t _H	10	0	_	
	15	0	_	



CD4508B Types

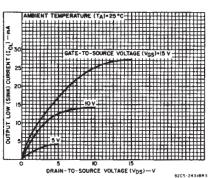


Fig.2 – Typical output low (sink) current characteristics.

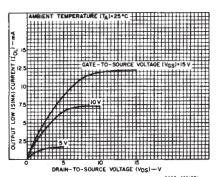


Fig.3 – Minimum output low (sink) current characteristics.

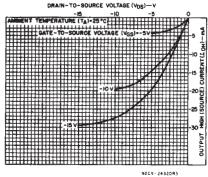


Fig.4 — Typical output high (source) current characteristics.

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STATIC ELECTRICAL CHARACTERISTICS

CHARACTER-	CONE	IS	LIMITS AT INDICATED TEMPERATURES (°C)							UNITS	
12116	Vo	VIN	V _{DD}	-55	-40	+85	+125	Min.	+25 Typ.	Max.	}
	(V)	(V)	5	5	5	150	150	171111.	-	-	-
Quiescent Device Current,	-	0,5	10	10	10	300	300	-	0.04	5 10	
IDD Max.		0,10	15	20	20	600	600	_	0.04	20	μА
	-	0,15	20	100	100	3000	3000	_	0.04	100	
	_									100	
Output Low (Sink) Current	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1		ľ
IOL Min.	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6		
	1.5	0,15	15	4.2	4	2.8	2.4	34	6.8		mA
Output High (Source) Current,	4,6	0,5	5	-0.64		-0.42	-0.36	-0.51	-1	-	'''^
	2.5	0,5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	-	
IOH Min.	9.5	0,10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	.'	
	13.5	0,15	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8		
Output Voltage: Low-Level,	-	0,5	5			.05		-	0	0,05	
VOL Max.		0,10	10			.05		-	0	0.05	
	-	0,15	15			.05		_	0	0.05	v -
Output Voltage:		0,5	5		4	.95		4.95	5	_	
High-Level, -VOH Min.		0,10	10		9	.95		9.95	10		
AOH MIII.	_	0,15	15		14	.95		14.95	15	±(** .	
Input Low	0.5, 4.5	_	5		1	.5		_	_	1.5	***
Voltage,	1, 9		10			3			- 122	3	6 × 40
VIL Max.	1.5,13.5	-	15			4	·	_		4	.,
Input High	0.5, 4.5	_	5		3	1.5		3.5	_	_	٧
Voltage,	1, 9	_	10			7		7		_	
VIH Min.	1.5,13.5	- -	15		•	1	,	11	_	_	
Input Current IJN Max.	-	0,18	18	±0.1	±0.1	±1	±1	-	±10 ⁻⁵	±0.1	μΑ
3-State Output Leakage Gurrent IOUT Max.	0,18	0,18	18	±0.4	±0.4	±12	±12	7	±10-4	±0.4	μΑ

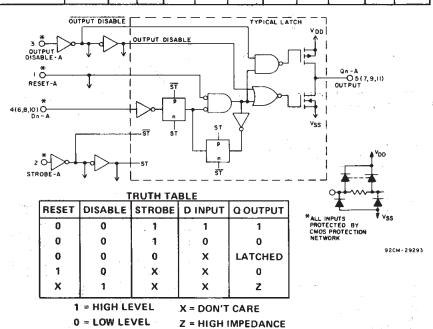


Fig. 7 — Logic diagram (A-Section), 1 of 4 identical latches with common output disable, reset, and strobe.

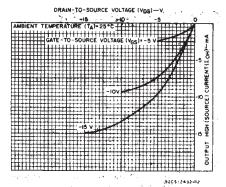


Fig. 4 — Minimum output high (source) current characteristics.

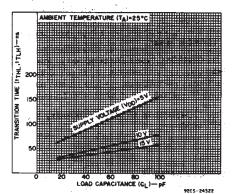


Fig. 5 — Typical transition time as a function of load capacitance.

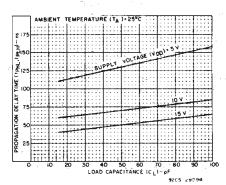


Fig. 6 — Typical propagation delay time as a function of load capacitance (strobe to data out).

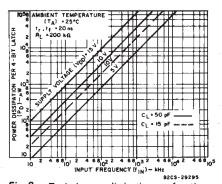
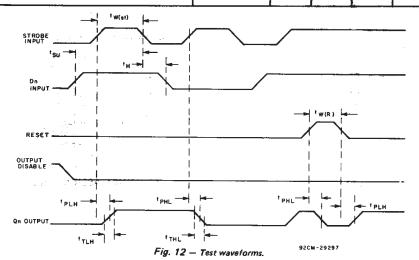


Fig. 8 — Typical power dissipation as a function of frequency.

CD4508B Types

DYNAMIC ELECTRICAL CHARACTERISTICS at T_A = 25°C; Input t_r, t_f = 20 ns, C_L = 50 pF, R_L = 200 k Ω , unless otherwise specified.

CHARACTERISTIC	TEST		Lin	MITS			
CHARACTERISTIC	CONDITIONS	VDD	Тур.	Max.	UNITS		
		5	100	200			
Transition Time, tth, ttl	İ	10	50	100	5		
		15	40	80			
		5	100	200	1		
Minimum Reset Pulse Width, tW(R)	İ	10	70	140	<u> </u>		
		15	50	100			
		5	70	140	ĺ		
Minimum Strobe Pulse Width, tW(st)		10	40	80			
	İ	15	35	70			
		5	25	50			
Minimum Setup Time, t _{SU}		10	15	30			
		15	10	20			
		5	0	0			
Minimum Hold Time, t _H		10	0	0	1		
		15	0	0			
Propagation Delay Times: tpHL,tpLH		5	130	260			
Strobe to Data Out		10	70	140			
4	ļ	15	50	100	ns		
		5	105	210			
Data In to Data Out		10	60	120	7		
		15	45	90			
	İ	5	90	180			
Reset to Data Out	1	10	50	100			
		15	40	80			
20th Brown St. D. L. Ti		5	90	180			
3-State Propagation Delay Times:		10	50	100			
Output High to High Impedance,tpHZ		15	35	70			
		5	90	180			
High Impedance to Output High, tpZH		10	50	100			
		15	35	70			
	111	5	90	180			
Output Low to High Impedance, tpLZ		10	50	100			
		15	35	70			
		5	90	180			
High Impedance to Output Low, tpZL		10	50	100			
Marie .		15	35	70			
Input Capacitance, CIN	Any Input	-	5	7.5	pF		
			1 1	i			



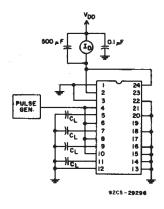


Fig.9 - Power dissipation test circuit.

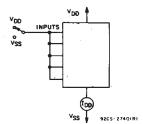


Fig. 10 — Quiescent device current test circuit.

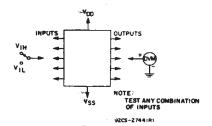


Fig. 11 - Input voltage test circuit.

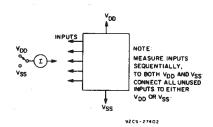


Fig. 13 - Input current test circuit.

CD4508B Types

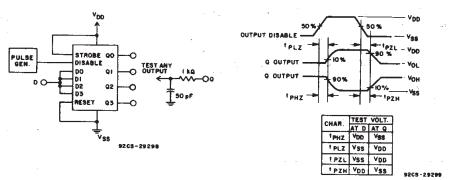


Fig. 14 - Output disable test circuit and waveforms.

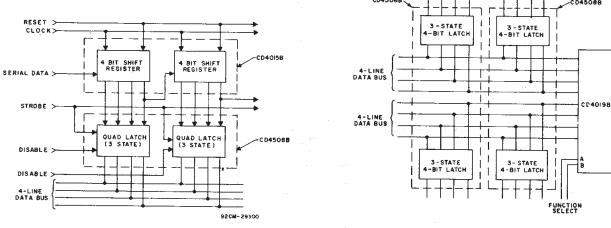
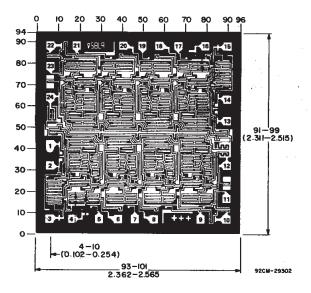


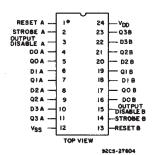
Fig. 15 - Bus register.



Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch) .

Chip dimensions and pad layout for CD4508B.

Fig.16 — Dual multiplexed bus register with function select.



92CM - 29301

DATA BUS

TERMINAL ASSIGNMENT







PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
CD4508BD3	ACTIVE	CDIP SB	JD	24	1	TBD	POST-PLATE	N / A for Pkg Type
CD4508BE	ACTIVE	PDIP	N	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD4508BEE4	ACTIVE	PDIP	N	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD4508BF3A	ACTIVE	CDIP	J	24	1	TBD	Call TI	N / A for Pkg Type
CD4508BM	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4508BM96	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4508BM96E4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4508BM96G4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4508BME4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4508BMG4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4508BNSR	ACTIVE	SO	NS	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4508BNSRE4	ACTIVE	SO	NS	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4508BNSRG4	ACTIVE	SO	NS	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4508BPW	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4508BPWE4	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4508BPWG4	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4508BPWR	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4508BPWRE4	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4508BPWRG4	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.



PACKAGE OPTION ADDENDUM

18-Sep-2008

package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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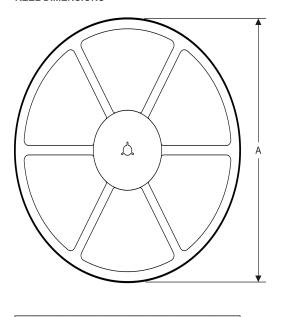
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PACKAGE MATERIALS INFORMATION

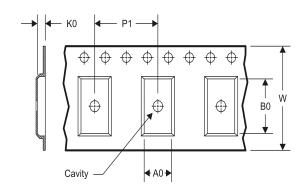
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TAPE AND REEL INFORMATION

REEL DIMENSIONS



TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD4508BM96	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
CD4508BNSR	SO	NS	24	2000	330.0	24.4	8.2	15.4	2.5	12.0	24.0	Q1
CD4508BPWR	TSSOP	PW	24	2000	330.0	16.4	6.95	8.3	1.6	8.0	16.0	Q1

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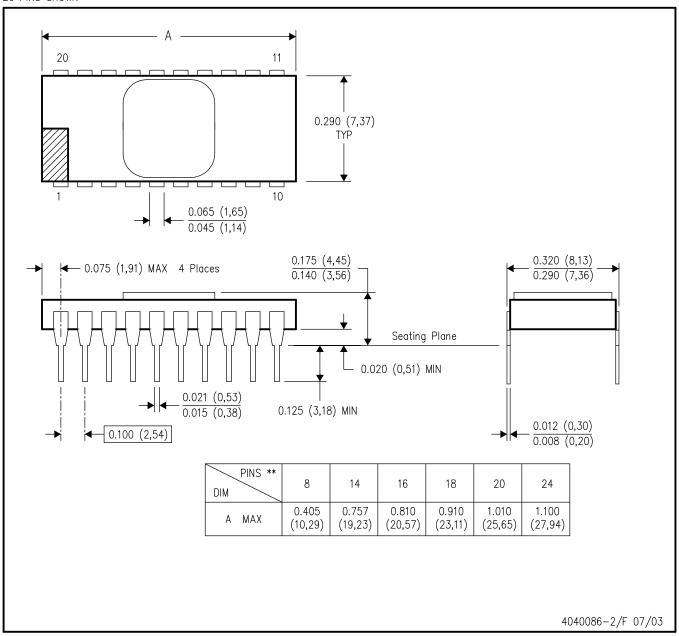
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD4508BM96	SOIC	DW	24	2000	367.0	367.0	45.0
CD4508BNSR	SO	NS	24	2000	367.0	367.0	45.0
CD4508BPWR	TSSOP	PW	24	2000	367.0	367.0	38.0

JD (R-CDIP-T**)

CERAMIC SIDE-BRAZE DUAL-IN-LINE PACKAGE

20 PINS SHOWN



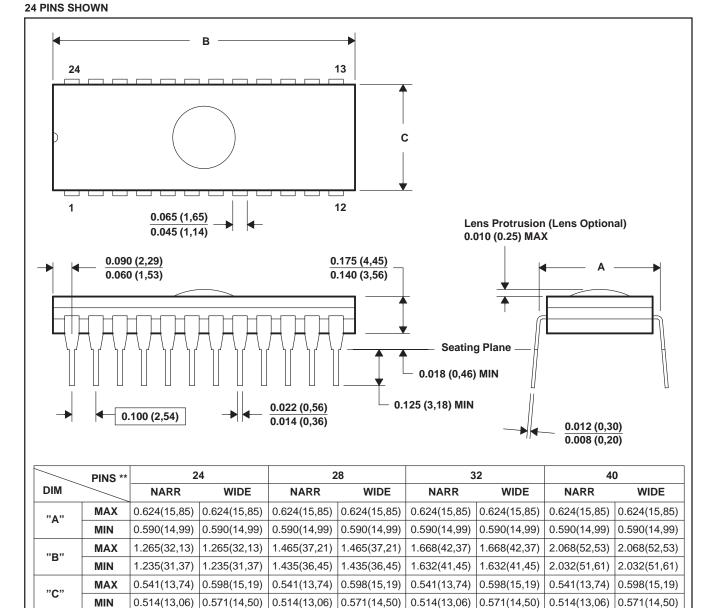
- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a metal lid.
- D. The terminals are gold plated.
- E. Falls within MIL STD 1835 CDIP2 T8, T14, T16, T18, T20 and T24 respectively.



4040084/C 10/97

J (R-GDIP-T**)

CERAMIC DUAL-IN-LINE PACKAGE



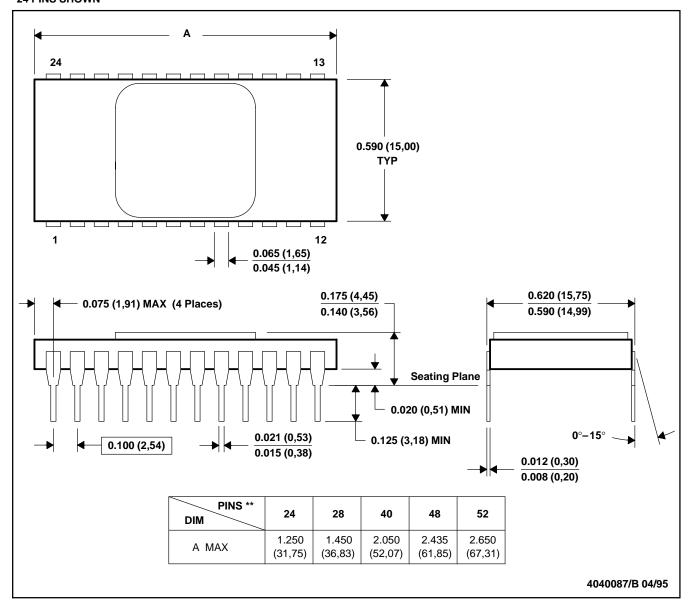
- B. This drawing is subject to change without notice.
- C. Window (lens) added to this group of packages (24-, 28-, 32-, 40-pin).
- D. This package can be hermetically sealed with a ceramic lid using glass frit.
- E. Index point is provided on cap for terminal identification.



JD (R-CDIP-T**)

24 PINS SHOWN

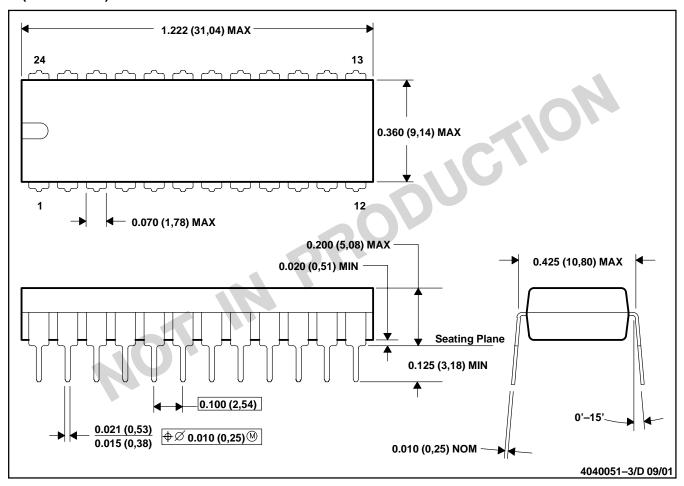
CERAMIC SIDE-BRAZE DUAL-IN-LINE PACKAGE



- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a metal lid.
- D. The terminals are gold-plated.

N (R-PDIP-T24)

PLASTIC DUAL-IN-LINE

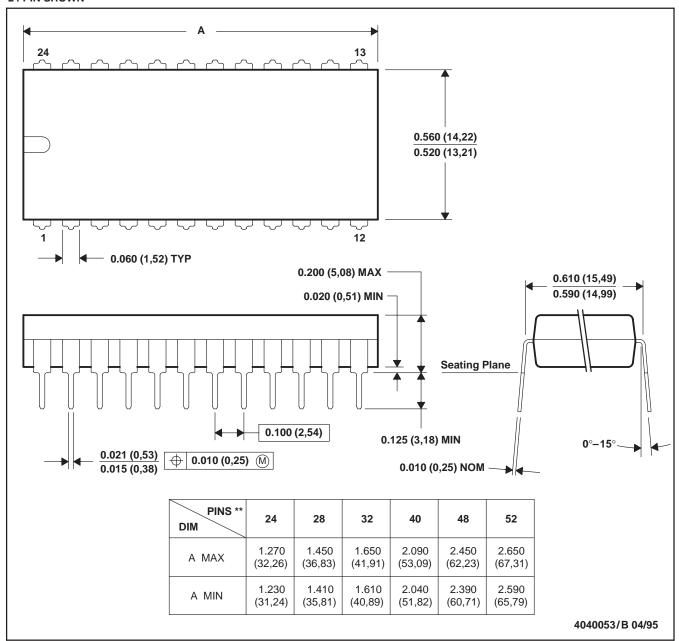


- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-010

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

24 PIN SHOWN



- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-011
- D. Falls within JEDEC MS-015 (32 pin only)



DW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AD.



PW (R-PDSO-G24)

PLASTIC SMALL OUTLINE

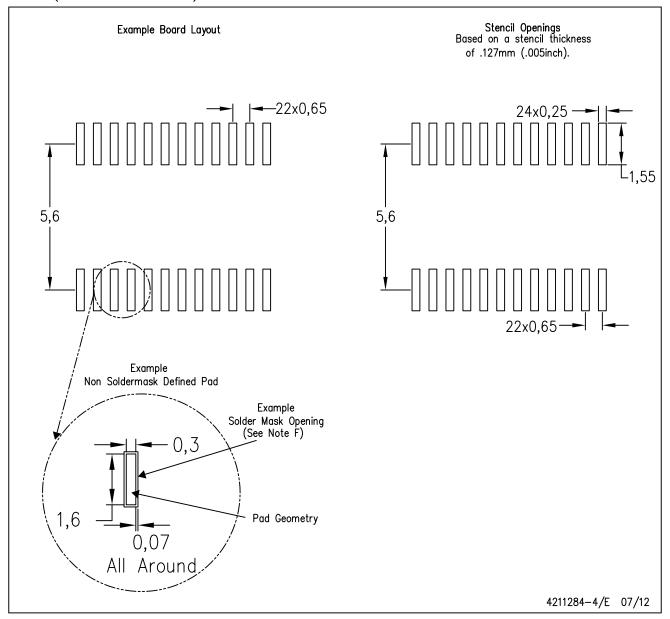


- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



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